TOSHIBA Photocoupler GaAs IRed & Photo-Transistor

# **TLP630**

Programmable Controllers AC / DC-Input Module Telecommunication

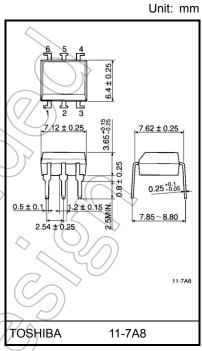
The TOSHIBA TLP630 consists of a photo-transistor optically coupled to two gallium arsenide infrared emitting diode connected inverse parallel in a six lead plastic DIP package.

- Collector-emitter voltage: 55 V (min)
- Current transfer ratio: 50% (min)

Rank GB: 100% (min)

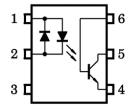
Isolation voltage: 5000 Vrms (min)

UL recognized: UL1577 file no. E67349



Weight: 0.4 g (typ.)

# Pin Configurations (top view)



1 : ANODE, CATHODE

2: CATHODE, ANODE

3 : N.C.

4 : EMITTER 5 : COLLECTOR

6: BASE

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Forward current		IF(RMS)	60	mA
	Forward current derating (Ta ≥ 39°C)	ΔIF/°C	-0.7	mA / °C
LED	Peak forward current (100 $\mu s$ pulse, 100 pps)	IFPT	±1	Α <
	Diode power dissipation	PD	100	mW
	Diode power dissipation derating (Ta $\ge$ 39 °C)	ΔP <sub>D</sub> /°C	-1.2	mW/°C
	Collector-emitter voltage	VCEO	55	Y
	Collector-base voltage	V <sub>CBO</sub>	80	N
_	Emitter-collector voltage	V <sub>ECO</sub>	7	V
Detector	Emitter-base voltage	V <sub>EBO</sub>	7	(v)
De	Collector current	Ic	50	mA
	Power dissipation	PC	150	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP <sub>C</sub> / °C	(-1.5/	mW / °C
Operating temperature range		Topr	-55 to 100	°C
Storage temperature range		T <sub>stg</sub>	-55 to 125	°C
Lead soldering temperature (10 s)		Tsol	260	°C(
Junction temperature		Fi	125	(°C)
Total package power dissipation		Pτ	250	mW
Total package power dissipation derating (Ta ≥ 25°C)		ΔP <sub>T</sub> /°C	-2.5	mW / °C
Isolation voltage (AC, 60 s, R.H. ≤ 60%) (Note 1)		BVS	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: LED side pins Shorted together and DETECTOR side pins shorted together.

#### **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	24	V
Forward current	IF(RMS)	_	16	25	mA
Collector current	lc	_	1	10	mA
Operating temperature	Topr	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

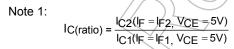
## **Electrical Characteristics (Ta = 25°C)**

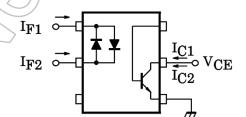
	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	IF = 10mA	1.0	1.15	1.3	V
LED	Forward current	lF	V <sub>F</sub> = 0.7V	_	2.5	10	μΑ
	Capacitance	CT	V = 0 V, f = 1MHz	_ <	60		pF
	Collector-emitter breakdown voltage	V(BR)CEO	I <sub>C</sub> = 0.5mA	55			٧
Detector	Emitter-collector breakdown voltage	V(BR)ECO	IE = 0.1mA	7		)/_	٧
	Collector-base breakdown voltage	V(BR)CBO	IC = 0.1mA	80	7(	_	٧
	Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 0.1mA	\ <u>\</u> \\	)		٧
	Collector dark current ICEO	1	V <sub>CE</sub> = 24V	1	10	100	nA
		ICEO	V <sub>CE</sub> = 24V, Ta = 85°C	$\mathcal{A}$	2	50	μΑ
	Collector dark current	Ісво	V <sub>CB</sub> = 10V	)	0.1		nA
	Capacitance (collector to emitter)	CCE	V = 0 V, f = 1MHz	_	10	Y.F.	pF

# Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	Ic/I <sub>F</sub>	I <sub>F</sub> = ±5mA, V <sub>CE</sub> = 5V Rank GB	50		600 600	%
Saturated CTR	I <sub>C</sub> / I <sub>F(sat)</sub> <	IF = ±1mA, VCE = 0.4V		60	—	%
		Rank GB	30		_	
Base photo-current  Collector-emitter saturation	IPB	$I_F = \pm 5 \text{mA}, V_{CB} = 5 \text{V}$ $I_C = 2.4 \text{mA}, I_F = \pm 8 \text{mA}$	//	10	0.4	μA V
voltage Off-state collector current	VCE(sat)	V <sub>F</sub> = ±0.7V, V <sub>CF</sub> = 24V		1	10	ν μA
CTR symmetry	Ic(ratio)	Ic(IF = -5mA) /	0.33	1	3	μΛ —
CTK symmetry	(ratio)	$I_C(I_F = +5mA)$ (Note 1)	0.55	ı	3	

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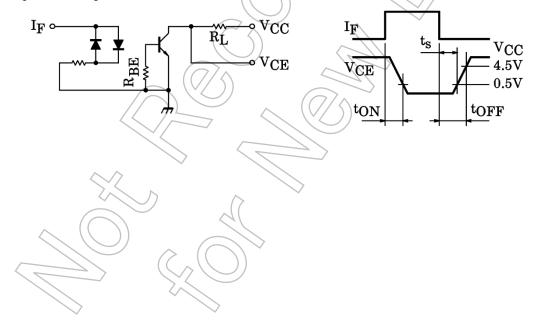
#### **Isolation Characteristics (Ta = 25°C)**

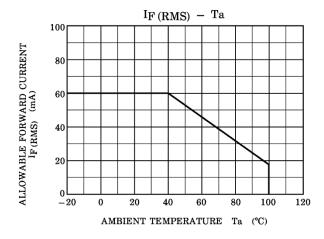
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	V <sub>S</sub> = 500V, R.H. ≤ 60%	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
		AC, 60 s	5000 <	_	_	\/
Isolation voltage	BVs	AC, 1 s, in oil	_	10000	_	Vrms
		DC, 60 s, in oil	_	10000	<del>\</del>	Vdc

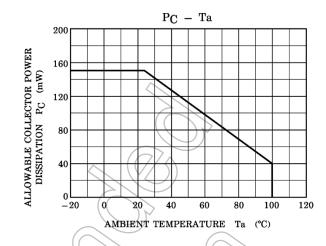
## **Switching Characteristics (Ta = 25°C)**

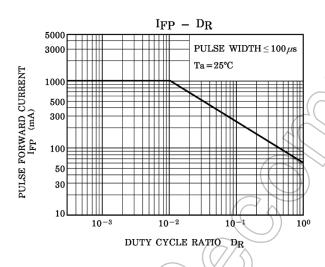
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	t <sub>r</sub>	V <sub>CC</sub> = 10V, I <sub>C</sub> = 2mA		2		
Fall time	t <sub>f</sub>		$\rightarrow$	3	2	
Turn-on time	ton	$R_L = 100\Omega$	> -	3	1	μs
Turn-off time	toff	$(\langle // \rangle)$	-0	3(	))70	
Turn-on time	ton	R <sub>L</sub> = 1.9 kΩ (Fig. 1) R <sub>BE</sub> = OPEN V <sub>CC</sub> = 5 V, I <sub>F</sub> = ±16mA	_	2	94)	/
Storage time	ts		-(	15	> _	μS
Turn-off time	toff		_(	25)	_	
Turn-on time	ton	$R_{L} = 1.9k\Omega$ (Fig. 1) $R_{BE} = 220k\Omega$ , $V_{CC} = 5 V$ $V_{F} = \pm 16mA$	(7)	2	_	
Storage time	ts		$(\vee)$	12	_	μS
Turn-off time	toff		<u></u>	20	_	

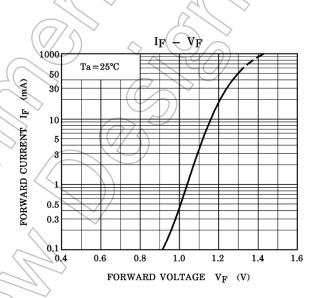
Fig. 1: Switching time test circuit

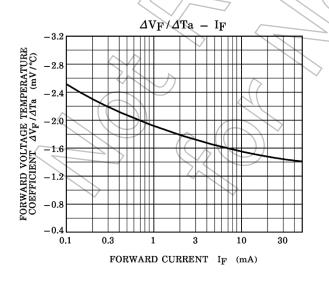


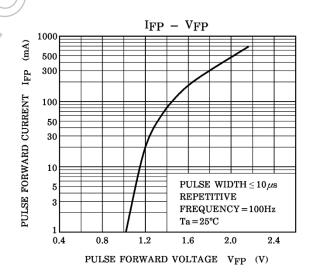


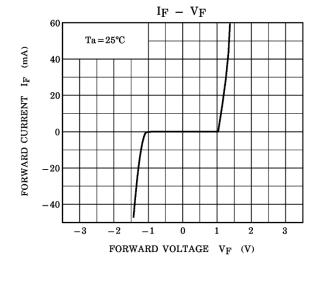


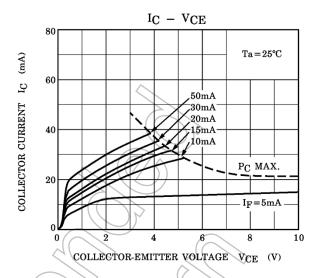


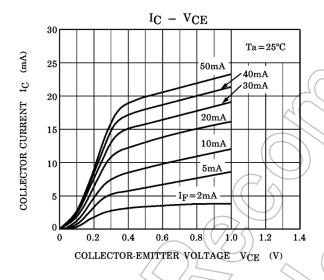


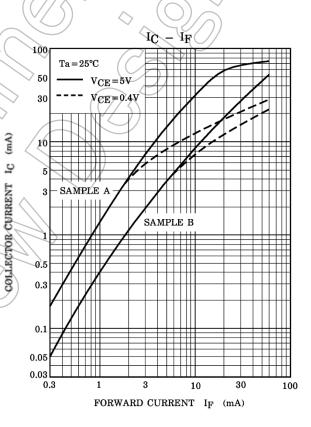


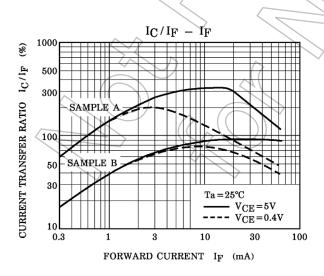




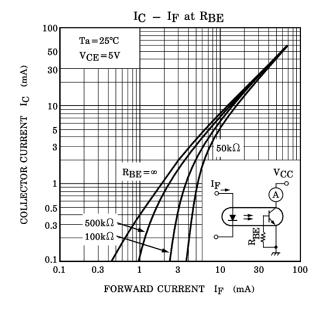


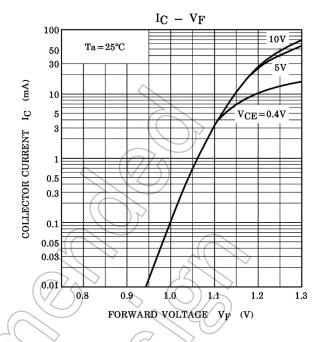


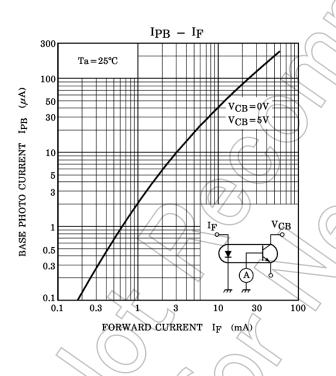


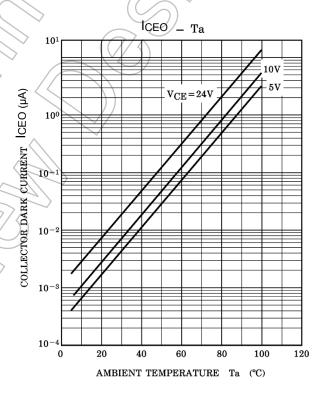


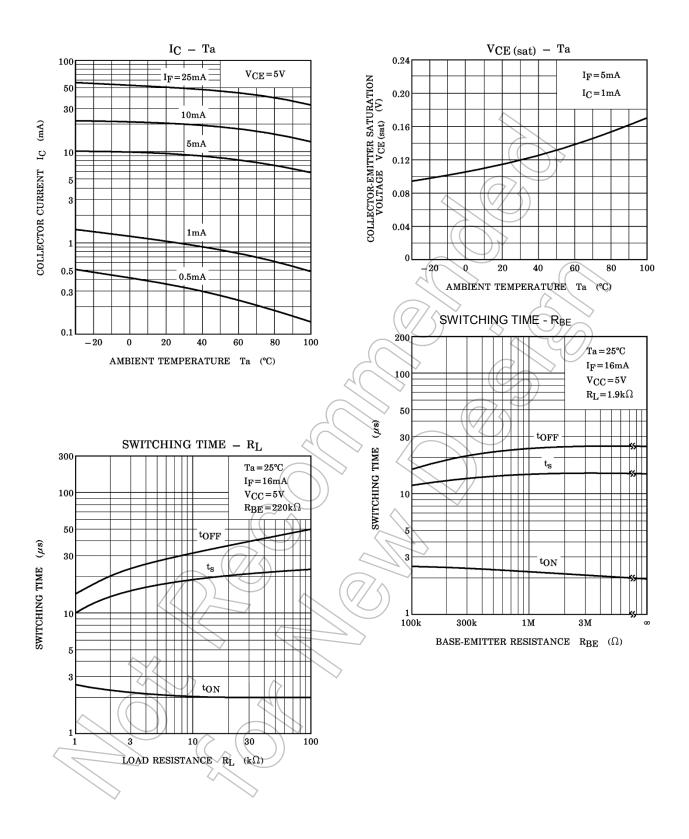
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